## NSN 5962-01-194-2947

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View Online at https://aerobasegroup.com/nsn/5962-01-194-2947 **Body Length:** 0.440 inches **Body Width:** Between 0.245 inches and 0.285 inches **Body Height:** Between 0.045 inches and 0.085 inches **Maximum Power Dissipation Rating:** 210.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Wsd: aircraft, f-16; aircraft, galaxy c-5 **Features Provided:** Low power and schottky and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Criticality Code Justification:** Feat **Case Outline Source And Designator:** F-5 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 65.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Ram **Special Features:** Weapon system essential **Test Data Document:** 13160-7564728 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Terminal Type And Quantity:** 

16 flat leads

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N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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